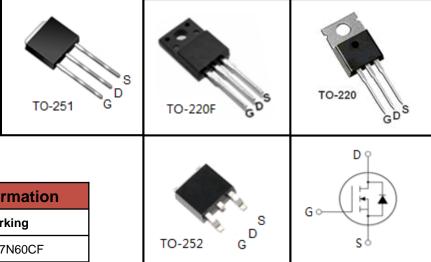
## **600V N-Channel MOSFET**

#### **FEATURES**

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information					
Device	Package	Marking			
CS7N60CF	TO-220F	CS7N60CF			
CS7N60CP	TO-220	CS7N60CP			
CS7N60CU	TO-251	CS7N60CU			
CS7N60CD	TO-252	CS7N60CD			

<b>Absolute Maximum Ratings</b> $T_C = 25^{\circ}C$ , unless otherwise noted							
Dozomotov	Symbol	Value					
Parameter		TO-220	TO-220F	TO-251	TO-252	Unit	
Drain-Source Voltage (V <sub>GS</sub> = 0V)	V <sub>DSS</sub>	600			V		
Continuous Drain Current	I <sub>D</sub>	7				Α	
Pulsed Drain Current (note1)	I <sub>DM</sub>	28			Α		
Gate-Source Voltage	V <sub>GSS</sub>	±30			V		
Single Pulse Avalanche Energy (note2)	E <sub>AS</sub>	180			mJ		
Avalanche Current (note1)	I <sub>AS</sub>	6			Α		
Repetitive Avalanche Energy (note1)	E <sub>AR</sub>	108			mJ		
Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>D</sub>	63		83		W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150				°C	

Thermal Resistance							
Barrier	Symbol		11				
Parameter		TO-220F	TO-251	TO-252	TO-220	Unit	
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	2.3		1.5		12.001	
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5	60		K/W		

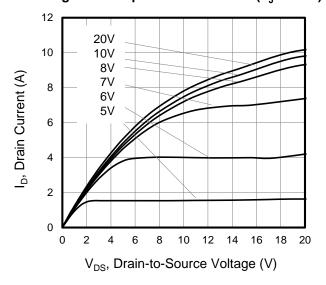
Specifications T <sub>J</sub> = 25°C, unless otherwise noted									
Parameter	Symbol	Test Conditions	Value			Unit			
	Gymbol	rest conditions	Min.	Тур.	Max.	Oilit			
Static									
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	600			V			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA			
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 30V$			±100	nA			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	3.0		4.0	V			
Drain-Source On-Resistance (Note3)	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_D = 3.5A$		1	1.2	Ω			
Dynamic									
Input Capacitance	C <sub>iss</sub>	V 0V		891		pF			
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 25V,$		97					
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		14					
Total Gate Charge	$Q_g$			30		nC			
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 480V, I_{D} = 7.0A,$ $V_{GS} = 10V$		5					
Gate-Drain Charge	$Q_{gd}$	65		14					
Turn-on Delay Time	t <sub>d(on)</sub>			38		ns			
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 300V, I_{D} = 7.0A,$		25					
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 25 \Omega$		154					
Turn-off Fall Time	t <sub>f</sub>			40					
Drain-Source Body Diode Character	istics								
Continuous Body Diode Current	I <sub>s</sub>				7.0	A			
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25 °C			28				
Body Diode Voltage	V <sub>SD</sub>	$T_J = 25^{\circ}\text{C}, I_{SD} = 3.5\text{A}, V_{GS} = 0\text{V}$			1.4	V			
Reverse Recovery Time	t <sub>rr</sub>	$V_{GS} = 0V, I_{S} = 7.0A,$		300		ns			
Reverse Recovery Charge	Q <sub>rr</sub>	$di_F/dt = 100A /\mu s$		1.59		μC			

#### Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L = 10.0mH,  $V_{DD}$  = 50V,  $R_G$  = 25  $\Omega$ , Starting  $T_J$  = 25  $^{\circ}C$
- 3. Pulse Test: Pulse width ≤ 300µs, Duty Cycle ≤ 1%

### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted

Figure 1. Output Characteristics (T<sub>J</sub> = 25°C)



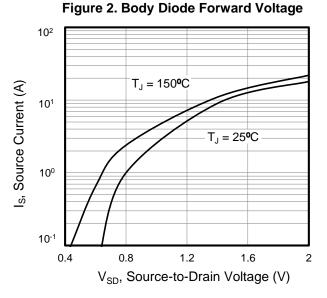


Figure 3. Drain Current vs. Temperature

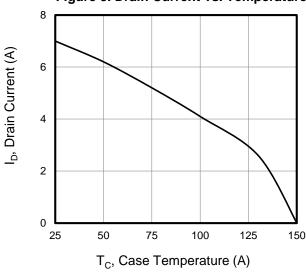


Figure 4.  $BV_{DSS}$  Variation vs. Temperature

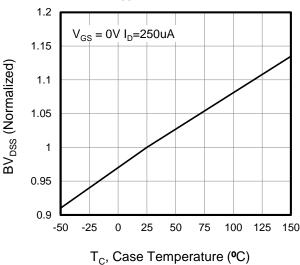


Figure 5. Transfer Characteristics

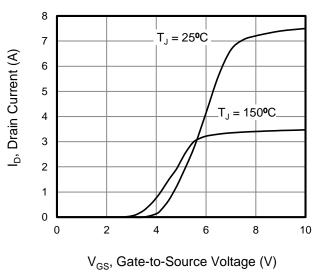
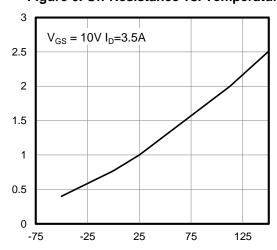


Figure 6. On-Resistance vs. Temperature

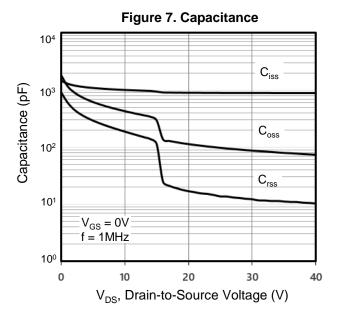


T<sub>J</sub>, Junction Temperature (°C)

R<sub>DS(on)</sub>, On-Resistance (Normalized)

10

### **Typical Characteristics** $T_J = 25^{\circ}\text{C}$ , unless otherwise noted



V<sub>GS</sub>, Gate-to-Source Voltage (V) 8 6 120V  $V_{DD} = 300V$ 4  $V_{DD} = 480V$ 2 0 0 5 10 15 20 25 30 Q<sub>q</sub>, Total Gate Charge (nC)

Figure 8. Gate Charge

Figure 9. Transient Thermal Impedance TO-220,TO-251,TO-252

10¹ Z<sub>thJC</sub>, Thermal Impedance (K/W) 100 10-1 D = 0.5D = 0.2D = 0.1D = 0.0510-2 D = 0.02D = 0.01Single Pulse 10-3 10-6 10-7 10-5 10-4 10-3 10<sup>-2</sup> 10-1 T<sub>p</sub>, Pulse Width (s)

Figure 10. Transient Thermal Impedance
TO-220F

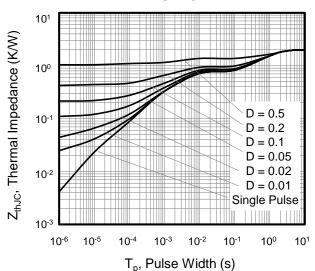


Figure A: Gate Charge Test Circuit and Waveform

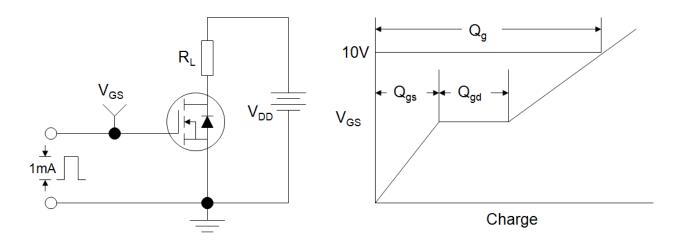


Figure B: Resistive Switching Test Circuit and Waveform

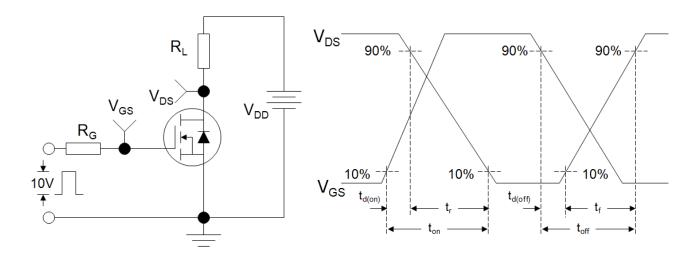
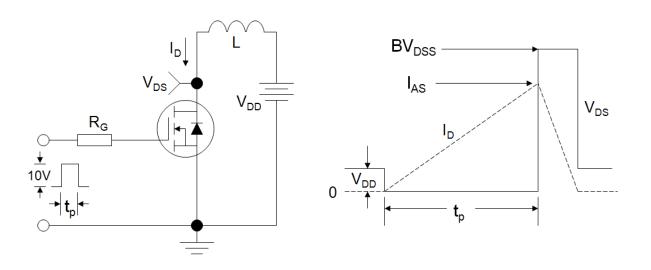
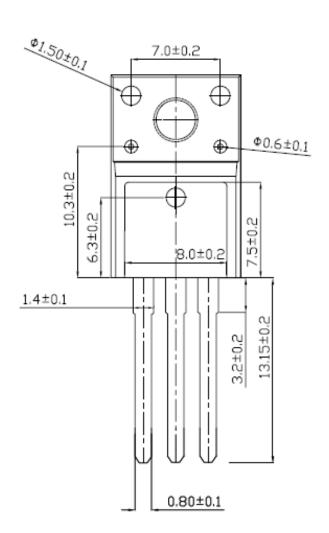
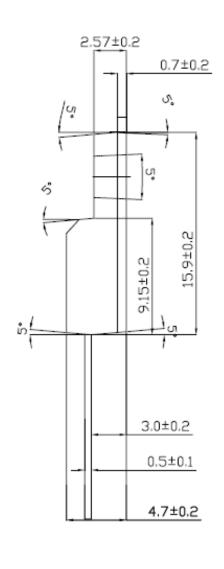


Figure C: Unclamped Inductive Switching Test Circuit and Waveform



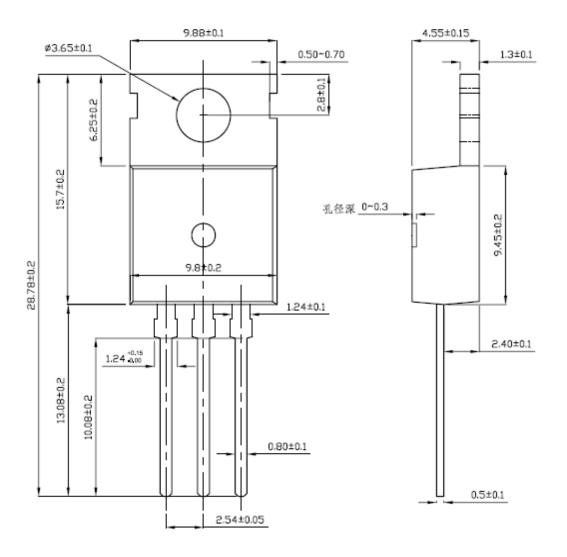
### **TO-220F**





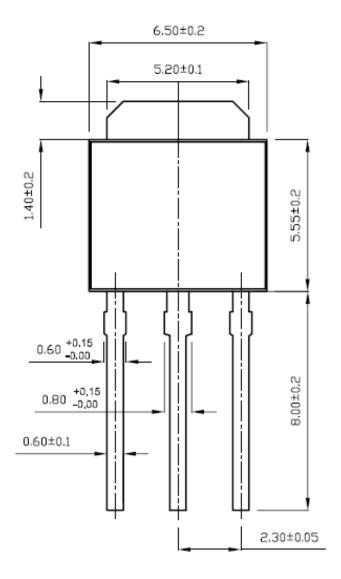


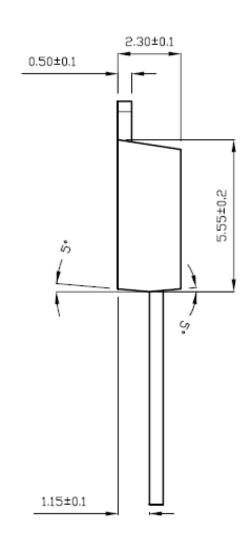
## **TO-220**



## CS7N65CU,CS7N65CD,CS7N65CF,CS7N65CP

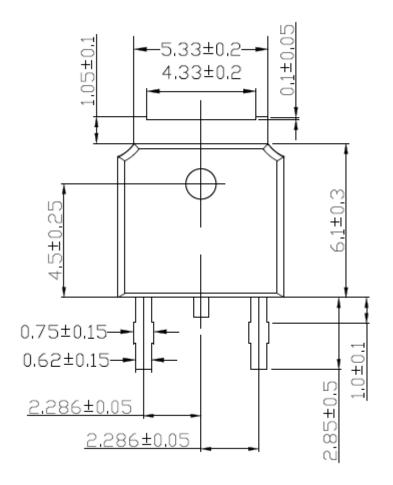
## **TO-251**

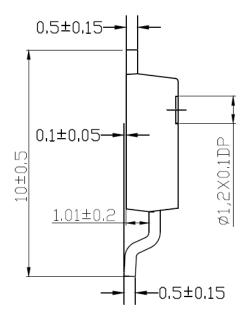


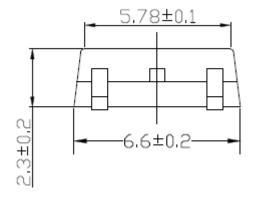




## **TO-252**









#### **Disclaimer**

All product specifications and data are subject to change without notice.

For documents and material available from this datasheet, Suzhou Convert does not warrant or assume any legal liability or responsibility for the accuracy, completeness of any product or technology disclosed hereunder.

No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document or by any conduct of Suzhou Convert.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless. Customers using or selling Suzhou Convert products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Suzhou Convert for any damages arising or resulting from such use or sale.

Suzhou Convert disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Suzhou Convert's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

Suzhou Convert SemiConductor CO., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

In the event that any or all Suzhou Convert products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. Suzhou Convert believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Convert Semiconductor manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60\_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3